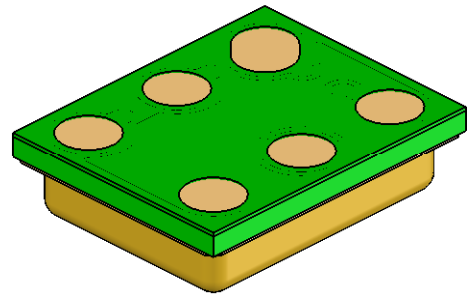
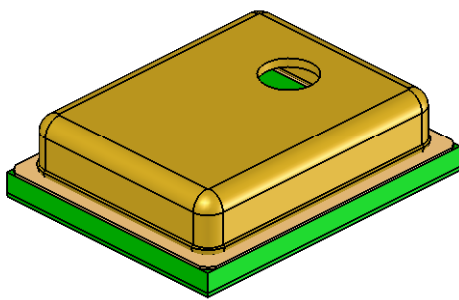


Digital "Mini" High SNR SiSonic™ Microphone
Specification



Knowles Acoustics
1151 Maplewood Drive
Itasca, IL 60143

1. DESCRIPTION AND APPLICATION

- 1.1 DESCRIPTION Digital "Mini" High SNR SiSonic™ Microphone Specification
- 1.2 APPLICATION Consumer electronics

2. PART MARKING

Identification Number Convention

S 1 2 3

4 5 6 7

S: Identification Marking

"S" - Knowles SiSonic Production

"E" - Knowles Engineering Samples

Digits 1-7: Job Identification Number

3. MATERIALS STATEMENT

3.1 Meets the requirements of the European RoHS directive, 2002/95/EC as amended.

3.2 Meets the requirements of the industry-standard IEC 61249-2-21:2003 for halogenated substances and Knowles Green Materials Standards Policy section on Halogen-Free.

3.3 Ozone depleting substances are not used in the product or the processes used to make the product, including compounds listed in annex A, B, and C of the "Montreal Protocol on Substances that deplete the Ozone Layer."

4. TEMPERATURE RANGE

4.1 Operating Temperature Range: -40°C to +100°C

4.2 Storage Temperature Range: -40°C to +100°C

5. ABSOLUTE MAXIMUM RATINGS

Parameter	Absolute Maximum Rating	Unit
CLOCK to Ground	-0.3, +5.0	V
SELECT, V _{DD} , DATA to Ground	-0.3, +5.0	V
Input Current	±5	mA
DATA Output Short Circuit	Indefinite to Ground or V _{DD}	

Stresses at these Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only. The device may not function when operated at these or any other conditions beyond those indicated under "Acoustic & Electrical Specifications". Exposure beyond those indicated under "Acoustic & Electrical Specifications" for extended periods may affect device reliability.

6. ACOUSTIC & ELECTRICAL SPECIFICATIONS

TEST CONDITIONS: 23 ±2°C, 60-70% R.H., V_{DD} = 1.8V, f_{clock}=2.4MHz, no load, unless otherwise specified

Parameter	Symbol	Condition	Limits			Unit
			Mn.	Nom.	Max.	
Supply Voltage ¹	V _{DD}		1.6	--	3.6	V
Current Consumption ^{1,5,6}	I _{DD}		--	--	600	µA
Sleep Current ^{1,6}	I _{SLEEP}	f _{clock} < 1kHz	--	25	45	µA
Directivity			Omni-directional			
Sensitivity ¹	S	94 dB SPL @ 1kHz	-25	-22	-19	dBFS
Signal to Noise Ratio	SNR	94 dB SPL @ 1kHz, A-weighted	--	61.5	--	dB(A)
Total Harmonic Distortion	THD	100 dB SPL @ 1kHz	--	--	1	%
		110 dB SPL @ 1kHz	--	--	10	%
Polarity		Increasing sound pressure	Decreasing density of 1's			
Fall-asleep Time ^{2,3}		V _{DD} = On, f _{clock} < 1kHz	--	--	10	ms
Wake-up Time ^{2,4}		V _{DD} = On, f _{clock} ≥ 1MHz	--	--	10	ms
Short Circuit Output Current	I _{SC}	Grounded output pin	--	1	10	mA
Output Load	C _{LOAD}		--	--	100	pF
Data Format			1/2 Cycle PDM			
Clock Frequency	f _{clock}		1.0	--	3.25	MHz
Clock Duty Cycle			40	--	60	%
Clock Rise Time	t _{cr}		--	--	10	ns
Clock Fall Time	t _{cf}		--	--	10	ns
Logic Input/Output Low	V _{IOL}	I _{out} = 1ma	-0.3	--	0.35xV _{DD}	V
Logic Input/Output High	V _{IOH}	I _{out} = 1ma	0.65xV _{DD}	--	V _{DD} +0.3	V
Delay Time for Valid Data	t _{dv}		18	--	60	ns
Delay time for High Z	t _{dz}		0	--	16	ns

¹ 100% tested

² Valid microphone states are: Powered Down mode (mic off), Sleep mode (low current, no output, fast startup), and Active mode (normal operation).

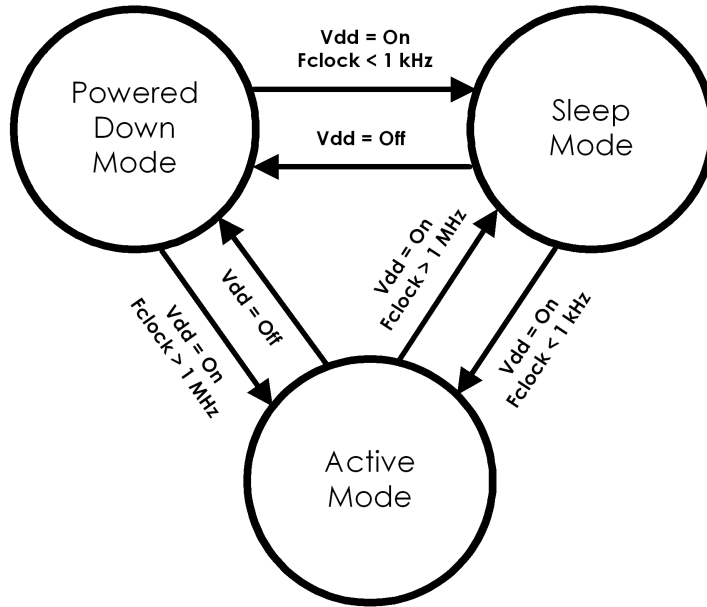
³ Time from f_{clock} < 1 kHz to Sleep Current specification is met when transitioning from Active to Sleep mode.

⁴ Time from f_{clock} ≥ 1 MHz to all applicable specifications are met when transitioning from Sleep to Active mode.

⁵ $\Delta I_{DD} = 0.5 * V_{DD} * C_{LOAD} * F_{CLOCK}$

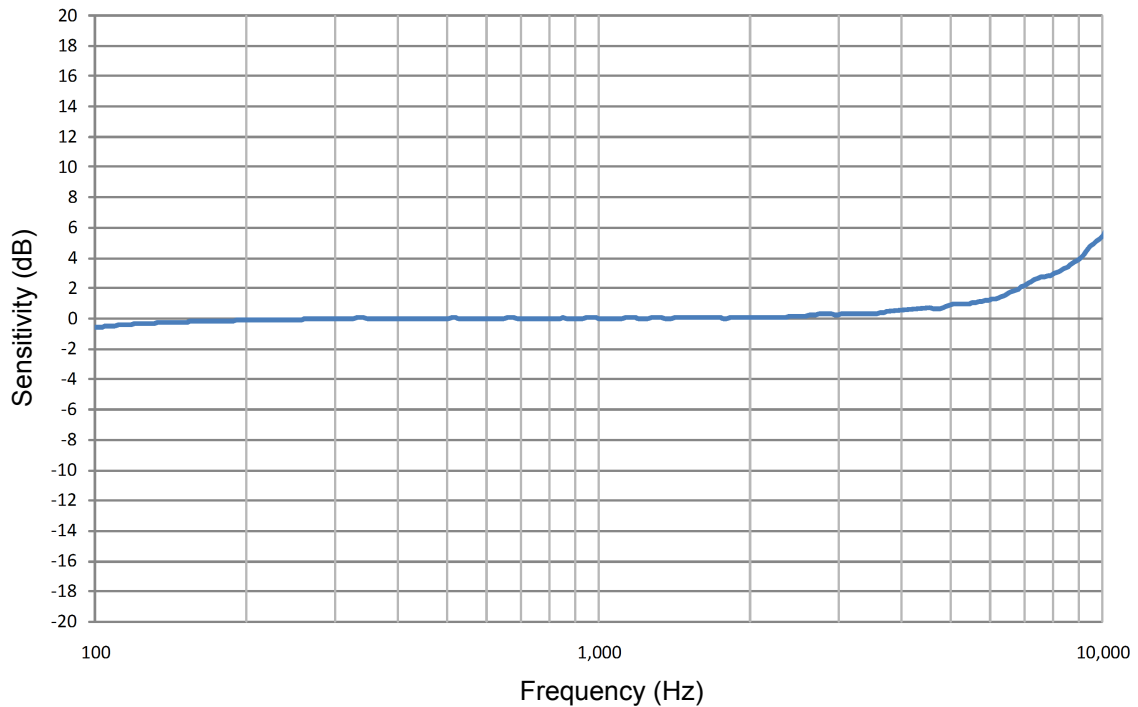
⁶ Specified max. values are measured at V_{DD} = 3.6V

7. MICROPHONE STATE DIAGRAM

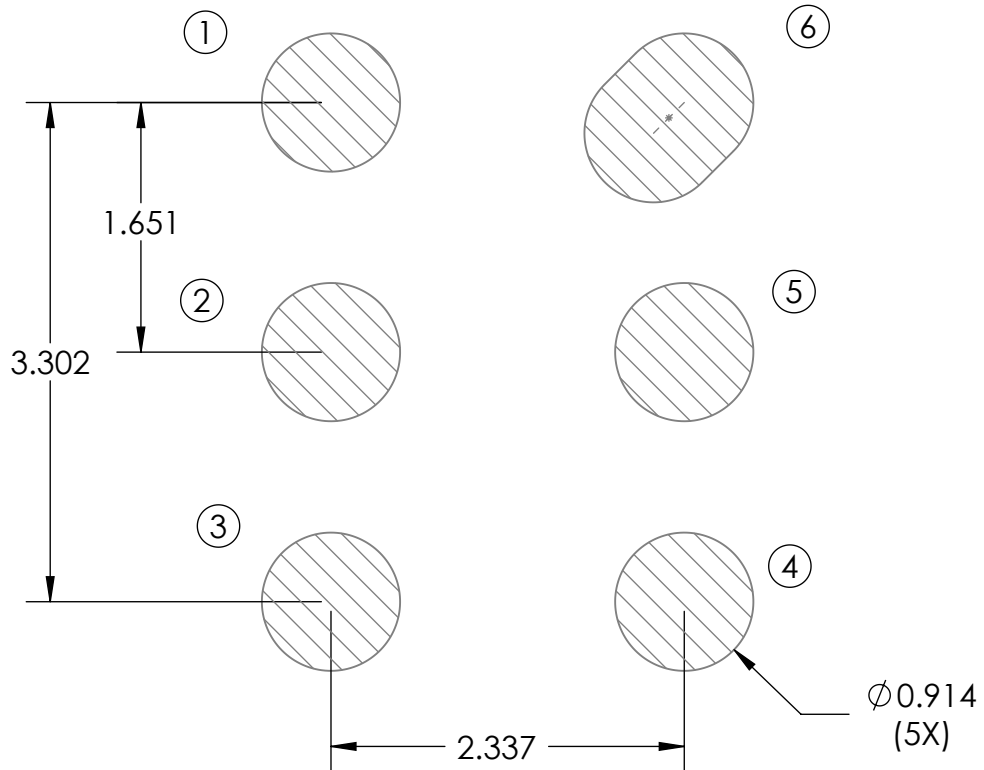


8. FREQUENCY RESPONSE CURVE

**TYPICAL FREE FIELD RESPONSE
NORMALIZED TO 1kHz**

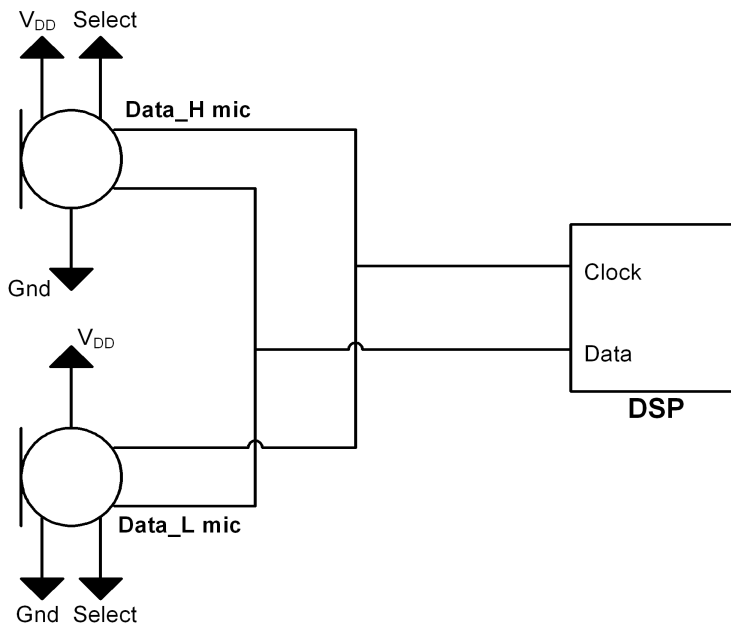


10. RECOMMENDED CUSTOMER LAND PATTERN



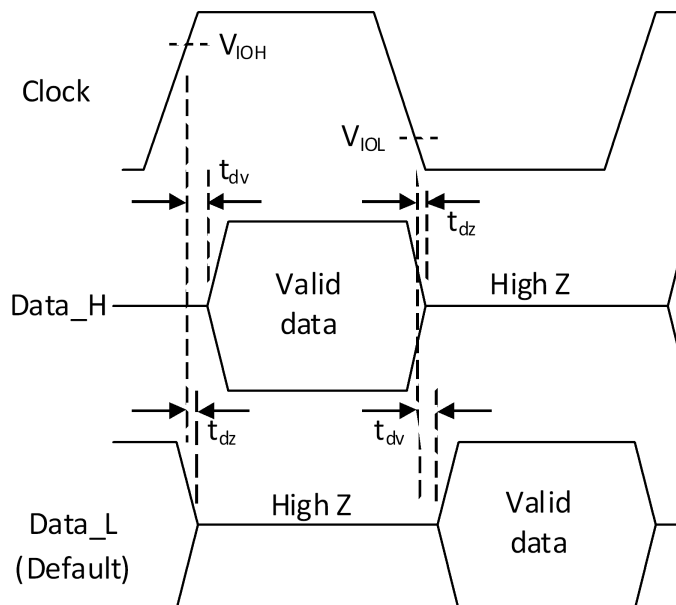
NOTE: Contact Knowles for Solder Stencil Information

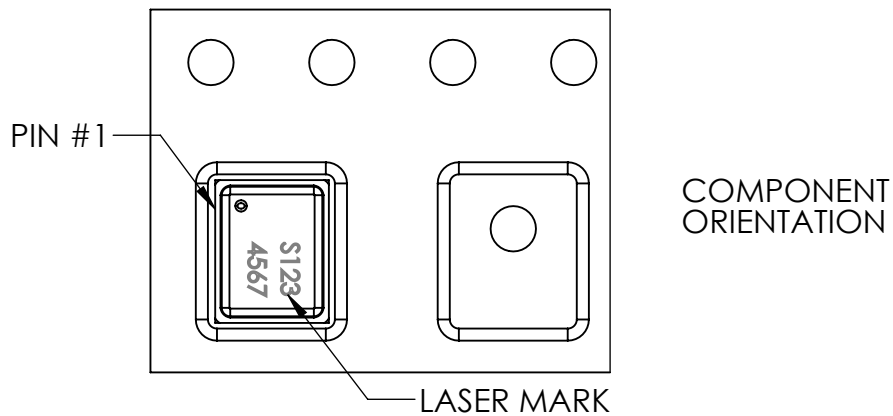
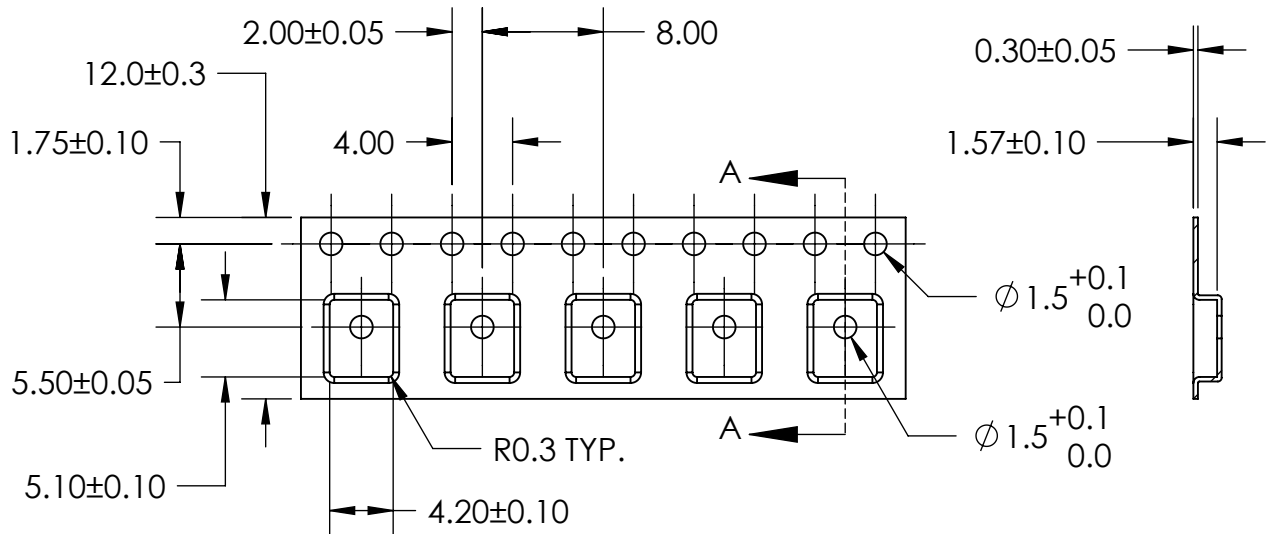
11. RECOMMENDED INTERFACE CIRCUIT & TIMING DIAGRAM



LABEL	Select	Drives data after	High-Z after
Data_H	High	Rising clock edge	Falling clock edge
Data_L	Low (default)	Falling clock edge	Rising clock edge

TIMING DIAGRAM



12. PACKAGING DETAIL


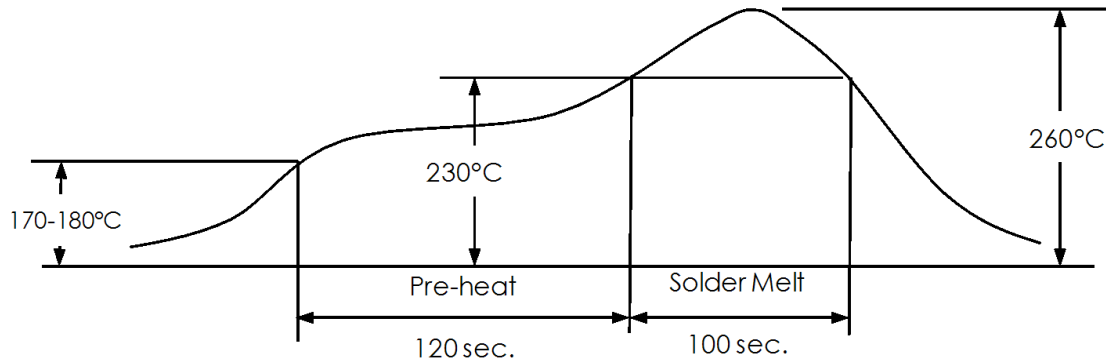
MODEL NUMBER	SUFFIX	REEL DIAMETER	QUANTITY PER REEL
SPM1423HM4H-B	-6	13"	4,800

TAPE & REEL	PER EIA-481
LABEL	LABEL APPLIED TO EXTERNAL PACKAGE & DIRECT TO REEL.

Note:

Dimensions are in millimeters unless otherwise specified.

13. SOLDER REFLOW PROFILE



Stage	Temperature Profile	Time (maximum)
Pre-heat	170 ~ 180°C	120 sec.
Solder Melt	Above 230°C	100 sec.
Peak	260°C maximum	30 sec.

14. ADDITIONAL NOTES

- (A) Shelf life: Twelve (12) months when devices are to be stored in factory supplied, unopened ESD moisture sensitive bag under maximum environmental conditions of 30°C, 70% R.H.
- (B) MSL (moisture sensitivity level) Class 2a.
- (C) Do not pull a vacuum over port hole of the microphone. Pulling a vacuum over the port hole can damage the device.
- (D) Do not board wash after the reflow process. Board washing and cleaning agents can damage the device. Do not expose to ultrasonic processing or cleaning.
- (E) Do not brush board after the reflow process. Brushing the board with/without solvents can damage the device.
- (F) Do not insert any object in port hole of device at any time as this can damage the device.
- (G) Number of reflow - Recommend no more than 3 cycles.
- (H) Do not apply air pressure into the port hole. Air pressure over psi can damage the device.

15. RELIABILITY SPECIFICATIONS

Note: After test conditions are performed, the sensitivity of the microphone shall not deviate more than 3dB from its initial value.

Test	Description
Thermal Shock	100 cycles of air-air thermal shock from -40°C to +125°C with 15 minute soaks. (IEC 68-2-4)
High Temperature Storage	+105°C environment for 1,000 hours. (IEC 68-2-2 Test Ba)
Low Temperature Storage	-40°C environment for 1,000 hours. (IEC 68-2-2 Test Aa)
High Temperature Bias	+105°C environment while under bias for 1,000 hours. (IEC 68-2-2 Test Ba)
Low Temperature Bias	-40°C environment while under bias for 1,000 hours. (IEC 68-2-2 Test Aa)
Temperature / Humidity Bias	+85°C/85% R.H. environment while under bias for 1,000 hours. (JESD22-A101A-B)
Vibration	4 cycles lasting 12 minutes from 20 TO 2,000 Hz in X, Y and Z direction with peak acceleration of 20g. (MIL 883E, Method 2007.2, A)
Electrostatic Discharge	3 discharges at +/-8kV direct contact to lid when unit is grounded (IEC 61000-4-2) and 3 discharges at +/-2kV direct contact to I/O pins. (MIL 883E, Method 3015.7)
Reflow	5 reflow cycles with peak temperature of +260°C.
Mechanical Shock	3 pulses of 10,000g in the X, Y and Z direction. (IEC 68-2-27, Test Ea)

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

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Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

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